

## CMPA2735015S

15 W, 2.7 - 3.5 GHz, GaN MMIC, Power Amplifier

Cree's CMPA2735015S is a gallium nitride (GaN) High Electron Mobility Transistor (HEMT) based monolithic microwave integrated circuit (MMIC). GaN has superior properties compared to silicon or gallium arsenide, including higher breakdown voltage, higher saturated electron drift velocity and higher thermal conductivity. GaN HEMTs also offer greater power density and wider bandwidths compared to Si and GaAs transistors. This MMIC contains a two-stage reactively matched amplifier design approach enabling high power and power added efficiency to be achieved in a 5mm x 5mm, surface mount (QFN package).



PN: CMPA2735015S

#### **Typical Performance Over 2.7-3.5 GHz** (T<sub>c</sub> = 25°C)

Parameter	2.7 GHz	2.9 GHz	3.1 GHz	3.3 GHz	3.5 GHz	Units
Small Signal Gain	35	34	34	34	33	dB
Saturated Output Power	21	21	24	25	22	W
Power Gain	27.3	27.2	27.9	27.9	27.5	dB
PAE	56	53	49	48	50	%

Note:  $P_{IN}$  = 16 dBm, Pulse Width = 500 µs; Duty Cycle = 10%

#### **Features**

- 33 dB Small Signal Gain
- 21 W Typical P<sub>SAT</sub>
- Operation up to 50 V .
- High Breakdown Voltage
- **High Temperature Operation**
- 5 mm x 5 mm Total Product Size

#### Applications



**Civil and Military Pulsed Radar Amplifiers** 

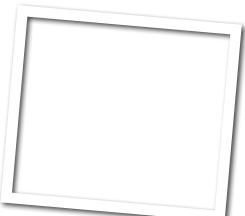


Figure 1.

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#### Absolute Maximum Ratings (not simultaneous) at 25°C

Parameter	Symbol	Rating	Units	Conditions	
Drain-source Voltage	V <sub>DSS</sub>	150	VDC	25°C	
Gate-source Voltage	V <sub>gs</sub>	-10, +2	VDC	25°C	
Storage Temperature	T <sub>stg</sub>	-65, +150	°C		
Operating Junction Temperature	TJ	225	°C		
Maximum Forward Gate Current	Ι <sub>G</sub>	3	mA	25°C	
Screw Torque	Т	40	in-oz		
Thermal Resistance, Junction to Case (packaged)	$R_{_{\!\Theta JC}}$	TBD	°C/W	300 µsec, 20%, 85°C	
Thermal Resistance, Junction to Case (packaged)	R <sub>eJC</sub>	TBD	°C/W	CW, 85°C	

### Electrical Characteristics (Frequency = 2.9 GHz to 3.5 GHz unless otherwise stated; $T_c$ = 25°C)

				ì		
Characteristics	Symbol	Min.	Тур.	Max.	Units	Conditions
DC Characteristics				1		
Gate Threshold Voltage	$V_{\rm GS(TH)}$	-3.8	-3.0	-2.3	V	$V_{\rm DS}$ = 10 V, I $_{\rm D}$ = 3 mA
Gate Quiescent Voltage	$V_{GS(Q)}$	-	-2.7	-	V <sub>DC</sub>	$V_{_{\rm DD}}$ = 50 V, $I_{_{\rm DQ}}$ = 80 mA, Freq = 2.9 GHz
Saturated Drain Current <sup>1</sup>	I <sub>DS</sub>	-	3	-	А	$V_{_{\rm DS}}$ = 6.0 V, $V_{_{\rm GS}}$ = 2.0 V
Drain-Source Breakdown Voltage	V <sub>BD</sub>	-	150	-	V	$V_{gs}$ = -8 V, I <sub>D</sub> = 3 mA
RF Characteristics <sup>2,3</sup>						
Small Signal Gain,	S21	-	35	-	dB	$V_{_{DD}}$ = 50 V, I $_{_{DQ}}$ = 80 mA, Freq = 2.7 GHz
Small Signal Gain <sub>2</sub>	S21	-	34	-	dB	$V_{_{DD}}$ = 50 V, I $_{_{DQ}}$ = 80 mA, Freq = 3.1 GHz
Small Signal Gain <sub>3</sub>	S21	-	33	-	dB	$V_{_{DD}}$ = 50 V, I $_{_{DQ}}$ = 80 mA, Freq = 3.5 GHz
Power Output <sub>1</sub>	P <sub>out</sub>	-	21	-	W	$V_{_{DD}}$ = 50 V, I $_{_{DQ}}$ = 80 mA, P $_{_{IN}}$ = 16 dBm, Freq = 2.7 GHz
Power Output <sub>2</sub>	P <sub>out</sub>	-	24	-	w	$V_{_{DD}}$ = 50 V, I $_{_{DQ}}$ = 80 mA, P $_{_{IN}}$ = 16 dBm, Freq = 3.1 GHz
Power Output <sub>3</sub>	P <sub>out</sub>	-	22	-	W	$V_{_{DD}}$ = 50 V, I $_{_{DQ}}$ = 80 mA, P $_{_{IN}}$ = 16 dBm, Freq = 3.5 GHz
Power Added Efficiency <sub>1</sub>	PAE	-	56	-	%	$V_{_{\rm DD}}$ = 50 V, $I_{_{\rm DQ}}$ = 80 mA, Freq = 2.7 GHz
Power Added Efficiency <sub>2</sub>	PAE	-	49	-	%	$V_{_{\rm DD}}$ = 50 V, $I_{_{\rm DQ}}$ = 80 mA, Freq = 3.1 GHz
Power Added Efficiency <sub>3</sub>	PAE	-	50	-	%	$V_{_{\rm DD}}$ = 50 V, $I_{_{\rm DQ}}$ = 80 mA, Freq = 3.5 GHz
Power Gain	G <sub>p</sub>	-	27	-	dB	$V_{_{DD}}$ = 50 V, $I_{_{DQ}}$ = 80 mA
Input Return Loss	S11	-	-8	-	dB	V <sub>DD</sub> = 50 V, I <sub>DQ</sub> = 80 mA
Output Return Loss	S22	-	-7	-	dB	V <sub>DD</sub> = 50 V, I <sub>DQ</sub> = 80 mA
Output Mismatch Stress	VSWR	-	-	5:1	Ψ	No damage at all phase angles, $V_{_{DD}}$ = 50 V, $I_{_{DQ}}$ = 80 mA, $P_{_{OUT}}$ = 15W Pulsed

Notes:

<sup>1</sup> Scaled from PCM data.

<sup>2</sup> All data tested in CMPA2735015S-AMP1

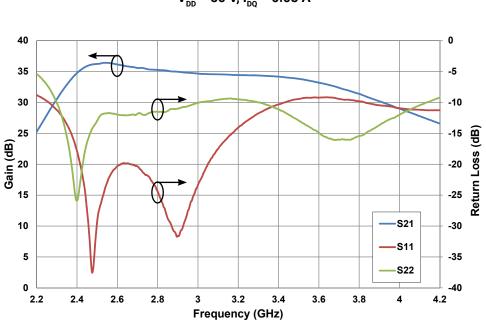
<sup>3</sup> Pulse Width = 500  $\mu$ s; Duty Cycle = 10%

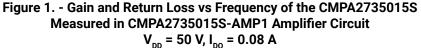
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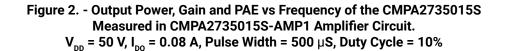
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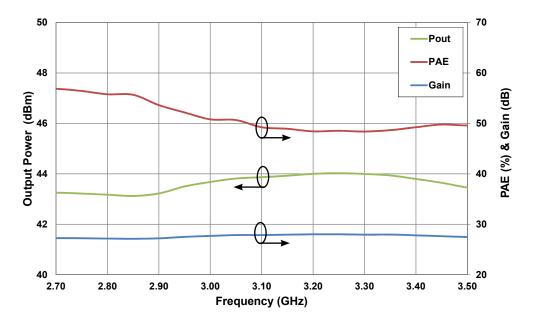


#### **Typical Performance of the CMPA2735015S**







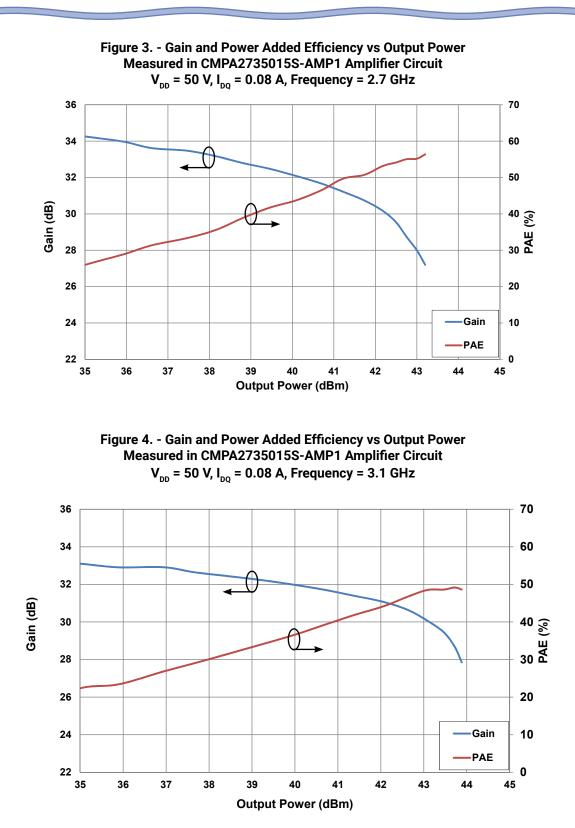


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#### **Typical Performance of the CMPA2735015S**



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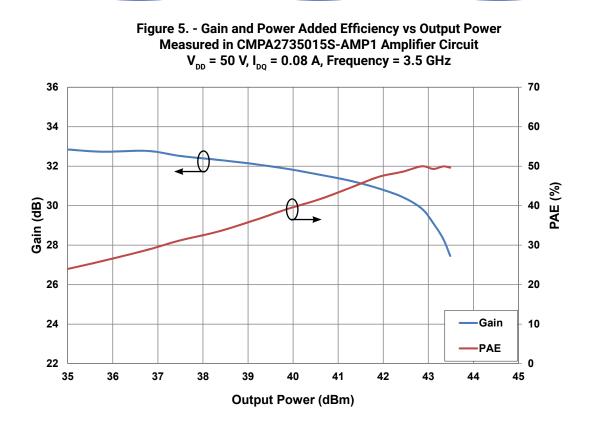
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CMPA2735015S Rev 0.0

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#### **Typical Performance of the CMPA2735015S**



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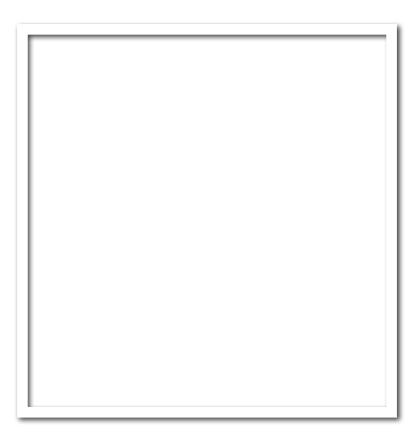
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#### CMPA2735015S-AMP1 Demonstration Amplifier Circuit Bill of Materials

Designator	Description	Qty
C1, C4, C10, C11	CAP, 470pF, 100V, 0603	1
C2, C3	CAP, 100pF, 100V, 0603	1
C5, C6, C8, C9	CAP, 10pF, 100V, 0402	1
C7	CAP, 33uF, 50V, ELECT, MVY, SMD	1
C12	CAP, 10uF, 16V, TANTALUM, SMD	1
R1, R2	RES, 1000hm, 1/16W, 0603	2
J1, J2	CONNECTOR, N-TYPE, FEMALE, W/0.500 SMA FLNG	1
J3, J4	CONNECTOR, HEADER, RT>PLZ .1CEN LK 5POS	1
-	PCB, RO4350B, E <sub>R</sub> = 3.48, h = 10 mil	1
Q1	CMPA2735015S	1

#### CMPA2735015S-AMP1 Demonstration Amplifier Circuit

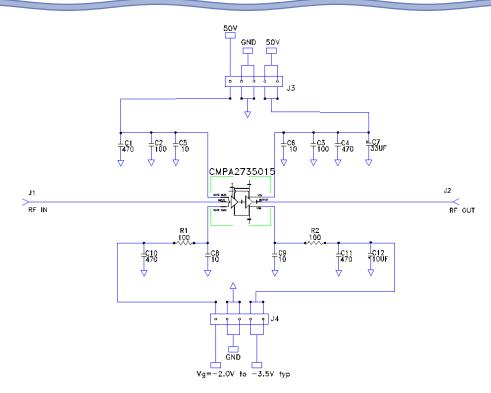


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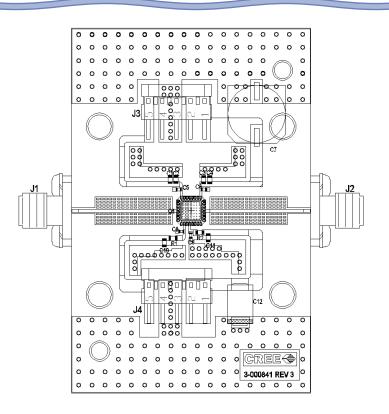
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#### CMPA2735015S-AMP1 Demonstration Amplifier Circuit Schematic



#### CMPA2735015S-AMP1 Demonstration Amplifier Circuit Outline



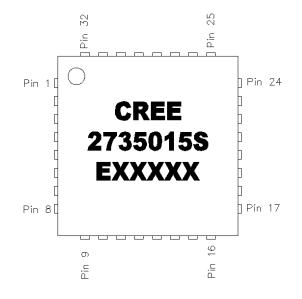
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### Product Dimensions CMPA2735015S (Package )

Pin	Input/Output	
1,2,3	NC	
4	RF IN	
5	RF IN	
6,7,8,9	NC	
10	VG1	
11	NC	
12	VG2	
13,14,15,16	NC	
17,18,19	NC	
20	RF OUT	
21	RF OUT	
22,23,24	NC	
25	VD2	
26,27,28,29	NC	
30,31	NC	
32	VD1	

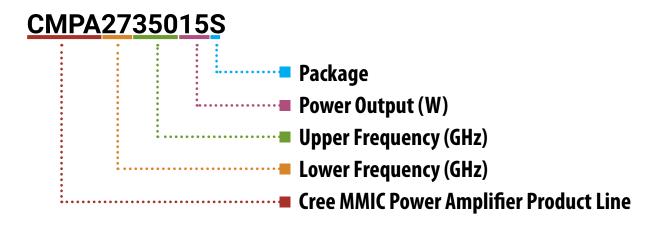


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Part Number System



Parameter	Value	Units
Lower Frequency	2.7	GHz
Upper Frequency	3.5	GHz
Power Output	15	W
Package	Surface Mount	-

#### Table 1.

**Note:** Alpha characters used in frequency code indicate a value greater than 9.9 GHz. See Table 2 for value.

Character Code	Code Value
А	0
В	1
С	2
D	3
E	4
F	5
G	6
н	7
J	8
К	9
Examples:	1A = 10.0 GHz 2H = 27.0 GHz

Table 2.

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#### **Product Ordering Information**

Order Number	Description	Unit of Measure	Image
CMPA2735015S	GaN HEMT	Each	2725004.43 276-104.43
CMPA2735015S-AMP1	Test board with GaN MMIC installed	Each	

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For more information, please contact:

Cree, Inc. 4600 Silicon Drive Durham, North Carolina, USA 27703 www.cree.com/RE

Sarah Miller Marketing Cree, RF Components 1.919.407.5302

Ryan Baker Marketing & Sales Cree, RF Components 1.919.407.7816

Tom Dekker Sales Director Cree, RF Components 1.919.407.5639

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